SCH1337

P-Channel Power MOSFET –30V, –2A, 150mΩ, Single SCH6



http://onsemi.com

Features

- ON-resistance RDS(on)1=115m Ω (typ.)
- · 4V drive
- · Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

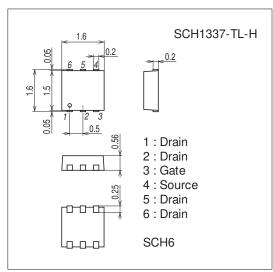
Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	VDSS		-30	V
Gate to Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-2	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-8	Α
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

This product is designed to "ESD immunity < 200V*", so please take care when handling.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

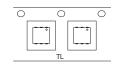
unit : mm (typ) 7028-002



Product & Package Information

Package : SCH6
 JEITA, JEDEC : SOT-563
 Minimum Packing Quantity : 5,000 pcs./reel

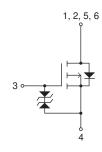
Packing Type: TL



Marking



Electrical Connection



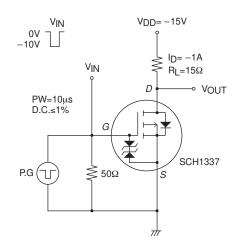
^{*} Machine Model

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Electrical Characteristics at Ta=25°C

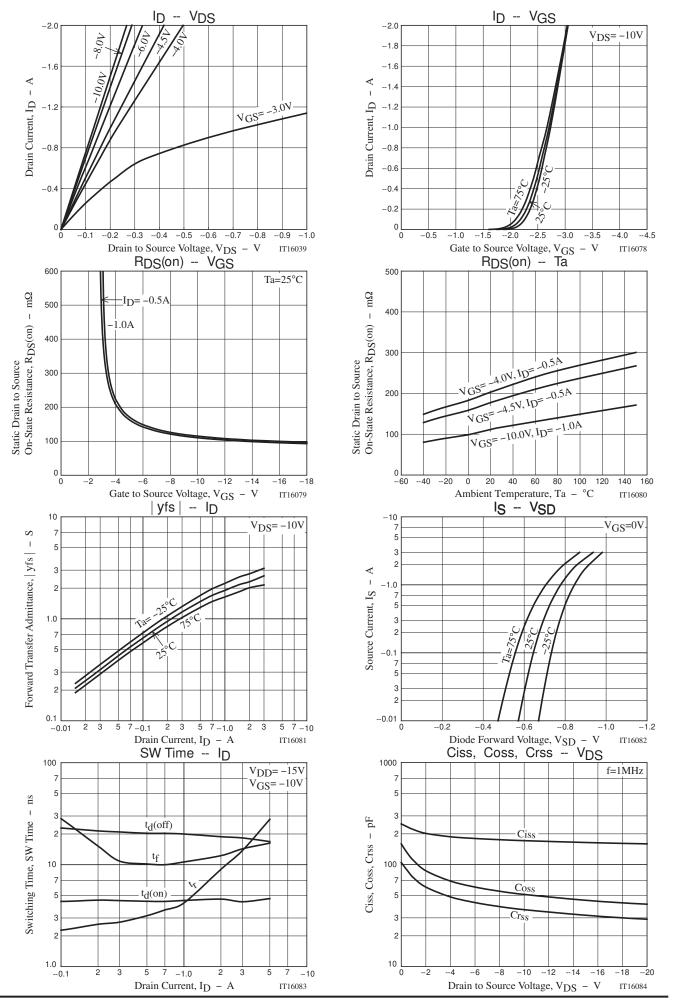
Parameter	Symbol	Conditions	Ratings			Unit
Farameter		Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-30V, V _{GS} =0V			-1	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA -1.2			-2.6	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-1A		1.9		S
	R _{DS} (on)1	I _D =-1A, V _G S=-10V		115	150	mΩ
Static Drain to Source On-State Resistance	R _{DS} (on)2	I _D =-0.5A, V _G S=-4.5V		182	255	mΩ
	R _{DS} (on)3	I _D =-0.5A, V _G S=-4V		208	292	mΩ
Input Capacitance	Ciss			172		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		51		pF
Reverse Transfer Capacitance	Crss			36		pF
Turn-ON Delay Time	t _d (on)			4.5		ns
Rise Time	t _r	Considered Took Consult		4.2		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		20		ns
Fall Time	tf			10.6		ns
Total Gate Charge	Qg			3.9		nC
Gate to Source Charge	Qgs	V _{DS} =-15V, V _{GS} =-10V, I _D =-2A		0.6		nC
Gate to Drain "Miller" Charge	Qgd]		0.8		nC
Diode Forward Voltage	V _{SD}	I _S =-2A, V _{GS} =0V		-0.86	-1.5	V

Switching Time Test Circuit

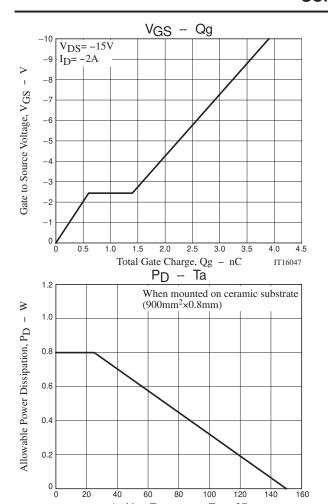


Ordering Information

Device	Package	Shipping	memo	
SCH1337-TL-H	SCH6	5,000pcs./reel	Pb-Free and Halogen Free	



SCH1337



20

60

80

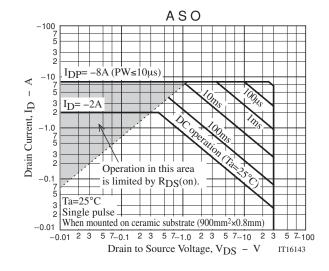
Ambient Temperature, Ta - °C

100

140

160

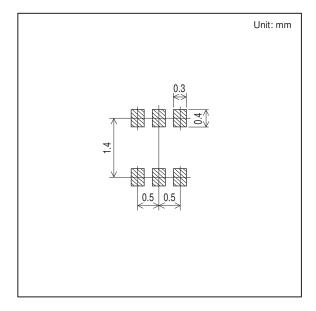
IT16049



Outline Drawing

SCH1337-TL-H

Land Pattern Example



Note on usage: Since the SCH1337 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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